# MN3208

# 2048-STAGE LOW VOLTAGE OPERATION LOW NOISE BBD

### ■ General description

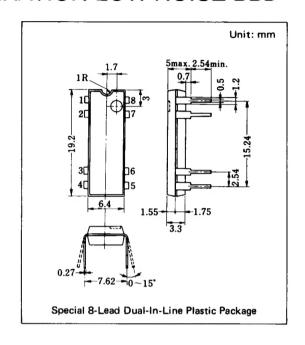
The NM3208 is a 2048-stage low voltage operation ( $V_{DD} = 5V$ ) low noise BBD that provides a signal delay of up to 102.4ms and is suitable as a device for generation of reverberation effect of audio equipment such as stereo equipments.

#### Features

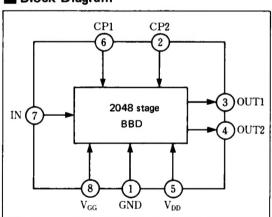
- Variable delay of audio signals: 10.24ms ~ 102.4ms.
- Wide supply voltage: 4 ~ 10V.
- Clock component cancellation capability.
- No insertion loss: L<sub>i</sub> = 0dB typ.
- Wide dynamic range: S/N = 71dB typ.
- Low distortion: THD = 0.5% typ. (V<sub>i</sub> = 0.25Vrms)
- N-channel silicon gate process.
- Special 8-lead dual-in-line plastic package.

### Applications

- Reverberation and echo effects of audio equipment such as radio cassette recorder, car radio, portable radio, portable stereo, echo microphone and pre-taped musical accompaniment (Karaoke), etc.
- Sound effect in electronic musical instruments.
- Variable or fixed delay of analog signals.
- Telephone time compression and delay line for voice communication system.



#### ■ Block Diagram



#### Quick Reference Data

ltem	Symbol	Value	Unit
Supply Voltage	V <sub>DD</sub> , V <sub>GG</sub>	+ 5, 14 V <sub>DD</sub>	V
Signal Delay Time	t <sub>D</sub>	10.24~102.4	ms
<b>Total Harmonic Distortion</b>	THD	0.5	%
Signal to Noise Ratio	S/N	71	dB

## ■ Absolute Maximum Ratings (Ta = 25°C)

ltem	Symbol	Ratings	Unit
Terminal Voltage	$V_{DD}, V_{GG}, V_{CP}, V_{I}$	-0.3~+11	V
Output Voltage	Vo	-0.3~+11	V
Operating Temperature	Topr	<b>−20~+60</b>	C
Storage Temperature	Tstg	<b>−55~+125</b>	Ĉ

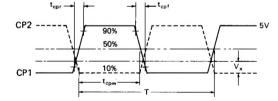
# **■ Operating Condition** (Ta = 25°C)

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Drain Supply Voltage	V <sub>DD</sub>		+4	+5	+10	V
Gate Supply Voltage	V <sub>GG</sub>			14 V <sub>DD</sub>		٧
Clock Voltage "H" Level	V <sub>CPH</sub>			V <sub>D</sub> D		٧
Clock Voltage "L" Level	V <sub>CPL</sub>		0		+1	٧
Clock Frequency	for		10		100	kHz
Clock Pulse Width *1	t <sub>CPW</sub>				0.5T *2	
Clock Rise Time *1	t <sub>CPr</sub>				500	ns
Clock Fall Time *1	topf				500	ns
Clock Input Capacitance	Сср				1400	рF
Clock Cross Point *1	V <sub>X</sub>		0		0.3V <sub>CPH</sub>	٧

# **Electrical Characteristics** ( $Ta=25^{\circ}C$ , $V_{DD}=V_{CPH}=+5V$ , $V_{CPL}=0V$ , $V_{GG}=\frac{14}{15}$ $V_{DD}$ , $R_{L}=100$ k $\Omega$ )

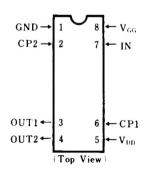
ltem	Symbol	Condition	Min.	Тур.	Max.	Unit
Signal Delay Time	t <sub>D</sub>		10.24		102.4	ms
Input Signal Frequency	fi	f <sub>cp</sub> = 40kHz, 3dB down (0dB at f <sub>i</sub> = 1kHz)	9			kHz
Input Signal Swing	Vi	THD=2.5%	0.36			Vrms
Insertion Loss	Li	f <sub>OP</sub> =40kHz, f <sub>i</sub> =1kHz	-4	0	4	dB
Total Harmonic Distortion	THD	$f_{OP}=40kHz$ , $f_i=1kHz$ , $V_i=0.25Vrms$		0.5	2.5	%
Noise	V <sub>no</sub>	f <sub>cp</sub> = 100kHz Weighted by "A" curve			0.3	mVrms
Signal To Noise Ratio	S/N	rcp - 100ktiz Weighted by A curve		71		dB

# \*1 Clock Pulse Waveforms

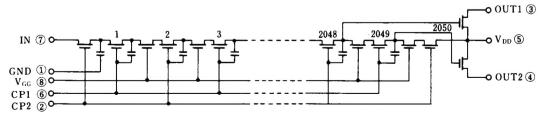


\*2 T = 1/f<sub>CP</sub> (Clock Period)

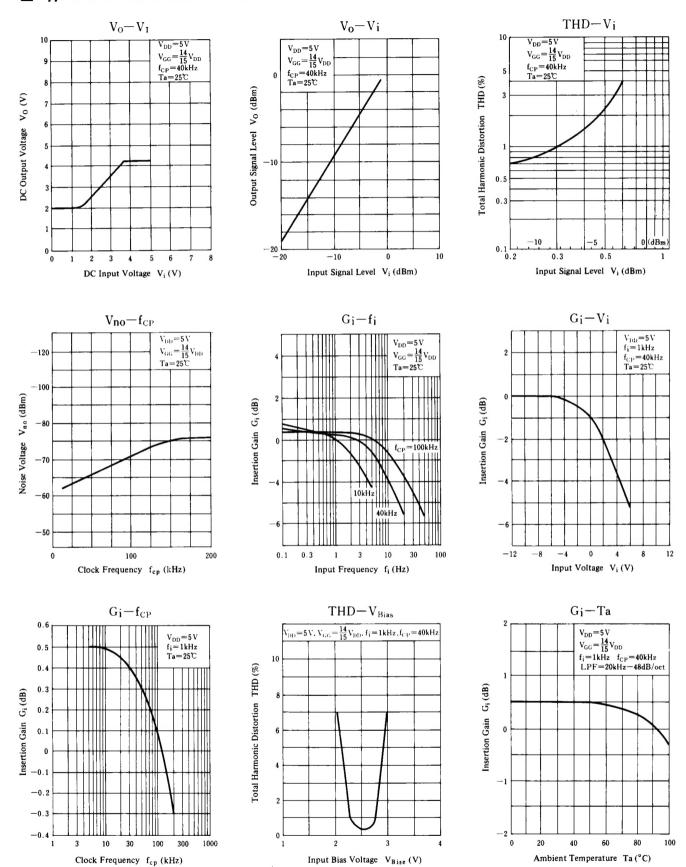
## Terminal Assignments

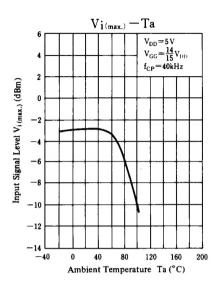


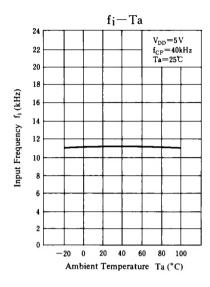
# ■ Circuit Diagram

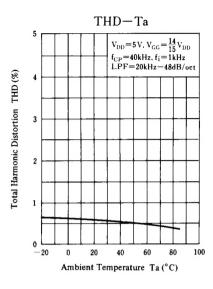


# **■ Typical Electrical Characteristic Curves**

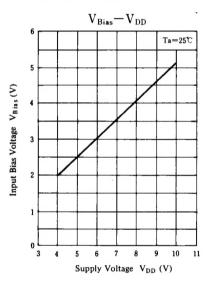


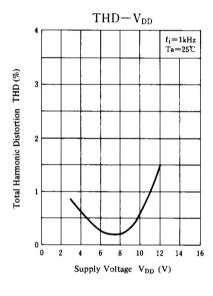


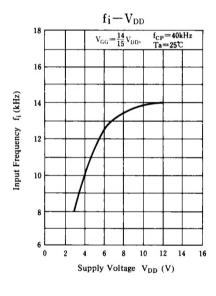


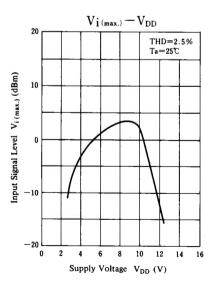


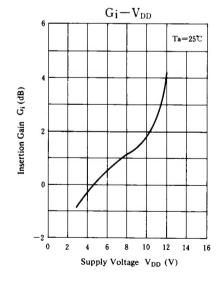
# ■ Supply Voltage Characteristics

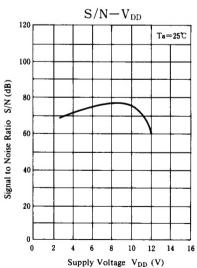




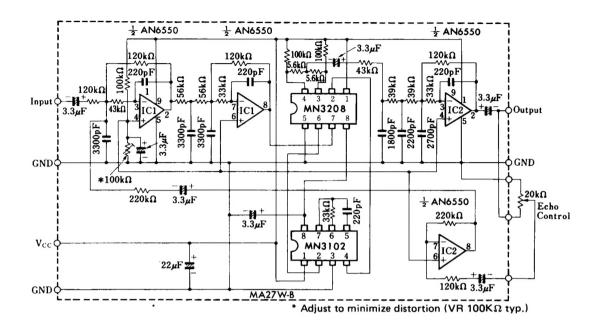








### ■ Application Circuit



Reverberation Effect Generation Circuit (Signal Delay Over 100msec.)